

Transistors

High frequency amplifier transistor, RF switching (6V, 50mA)

2SC4774 / 2SC4713K

●Features

- 1) Very low output-on resistance (Ron).
- 2) Low capacitance.

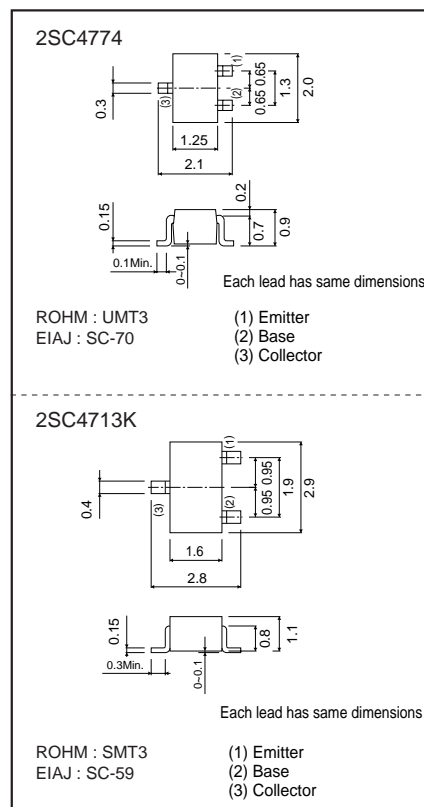
●Absolute maximum ratings (Ta=25°C)

| Parameter | Symbol | Limits | Unit |
|-----------------------------|------------------|-------------|------|
| Collector-base voltage | V _{CB0} | 12 | V |
| Collector-emitter voltage | V _{CE0} | 6 | V |
| Emitter-base voltage | V _{EB0} | 3 | V |
| Collector current | I _C | 50 | mA |
| Collector power dissipation | P _C | 0.2 | W |
| Junction temperature | T _j | 150 | °C |
| Storage temperature | T _{stg} | -55 to +150 | °C |

●Packaging specifications and hFE

| Type | 2SC4774 | 2SC4713K |
|------------------------------|---------|----------|
| Package | UMT3 | SMT3 |
| hFE | S | S |
| Marking | BM* | BM* |
| Code | T106 | T146 |
| Basic ordering unit (pieces) | 3000 | 3000 |

*Denotes hFE



●External dimensions (Unit : mm)

●Electrical characteristics (Ta=25°C)

| Parameter | Symbol | Min. | Typ. | Max. | Unit | Conditions |
|--------------------------------------|----------------------|------|------|------|------|---|
| Collector-base breakdown voltage | BV _{CB0} | 12 | — | — | V | I _C =10μA |
| Collector-emitter breakdown voltage | BV _{CE0} | 6 | — | — | V | I _C =1mA |
| Emitter-base breakdown voltage | BV _{EB0} | 3 | — | — | V | I _E =10μA |
| Collector cutoff current | I _{CB0} | — | — | 0.5 | μA | V _{CB} =10V |
| Emitter cutoff current | I _{EB0} | — | — | 0.5 | μA | V _{EB} =2V |
| Collector-emitter saturation voltage | V _{CE(sat)} | — | — | 0.3 | V | I _C /I _E =10mA/1mA |
| DC current transfer ratio | h _{FE} | 270 | — | 560 | — | V _{CE} /I _C =5V/5mA |
| Transition frequency | f _T | 300 | 800 | — | MHz | V _{CE} =5V, I _E =-10mA, f=200MHz |
| Output capacitance | C _{ob} | — | 1 | 1.7 | pF | V _{CB} =10V, I _E =0A, f=1MHz |
| Output-on resistance | R _{on} | — | 2 | — | Ω | I _E =3mA, V _I =100mVrms, f=500kHz |

Transistors

Electrical characteristic curves

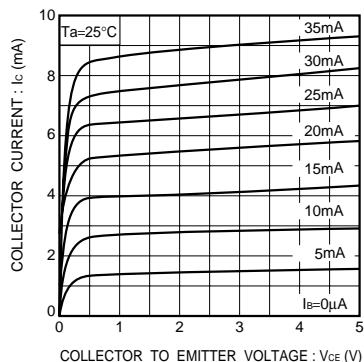


Fig.1 Grounded emitter output characteristics (I)

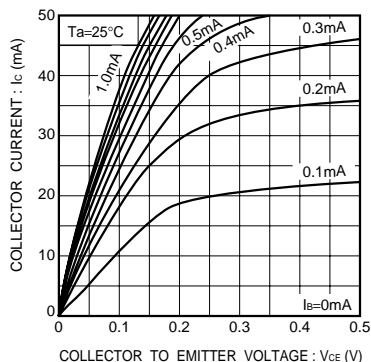


Fig.2 Grounded emitter output characteristics (II)

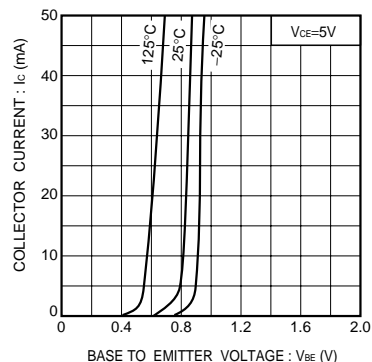


Fig.3 Grounded emitter propagation characteristics

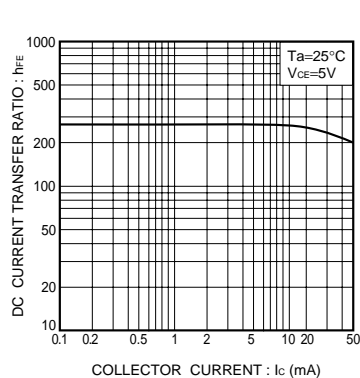


Fig.4 DC current gain vs. collector current

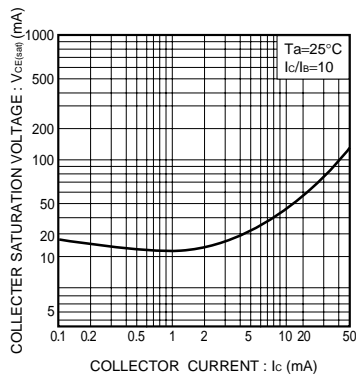


Fig.5 Collector-emitter saturation voltage vs. collector current

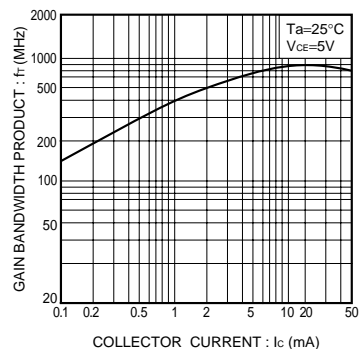


Fig.6 Gain bandwidth product vs. collector current

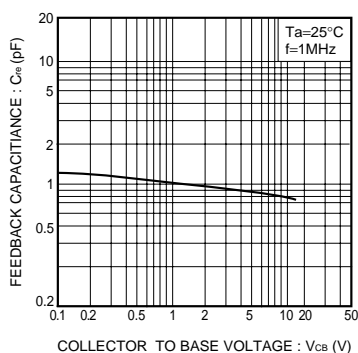


Fig.7 Collector output capacitance vs. voltage

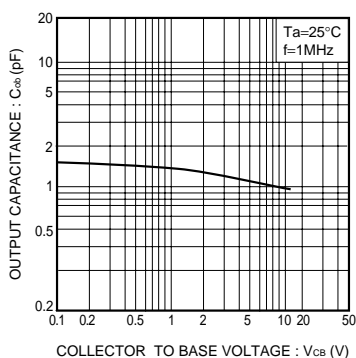


Fig.8 Back capacitance voltage

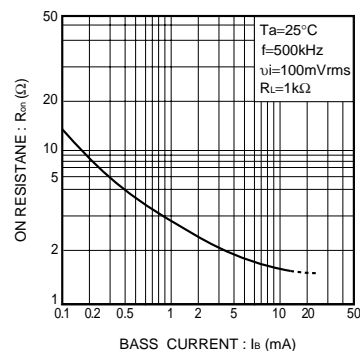


Fig.9 Output-on resistance vs. base current

Appendix

Notes

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